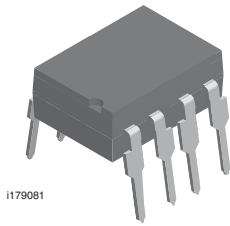
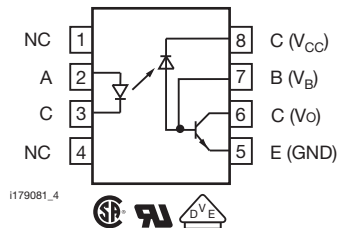


## High Speed Optocoupler, 1 MBd, Photodiode with Transistor Output



i179081



i179081\_4



### FEATURES

- Isolation test voltages: 5300 V<sub>RMS</sub>
- TTL compatible
- High bit rates: 1 Mbit/s
- High common-mode interference immunity
- Bandwidth 2 MHz
- Open-collector output
- External base wiring possible
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


**RoHS**  
COMPLIANT

### DESCRIPTION

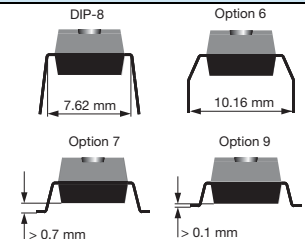
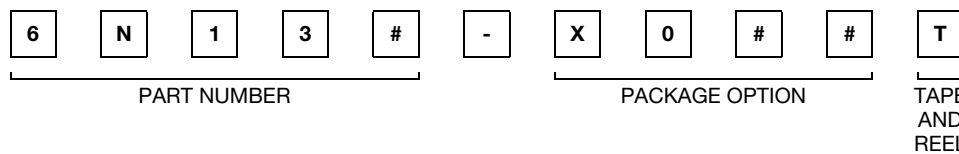
The 6N135 and 6N136 are optocouplers with a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector which consists of a photo diode and a high-speed transistor in a DIP-8 plastic package.

Signals can be transmitted between two electrically separated circuits up to frequencies of 2 MHz. The potential difference between the circuits to be coupled should not exceed the maximum permissible reference voltages.

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H double protection
- DIN EN 60747-5-2 (VDE0884)/DIN EN 60747-5-5 (pending), available with option 1
- CSA 93751

### ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)	
<b>UL, CSA</b>	<b>≥ 7</b>	<b>≥ 19</b>
DIP-8	6N135	6N136
DIP-8, 400 mil, option 6	-	6N136-X006
SMD-8, option 7	6N135-X007T <sup>(1)</sup>	6N136-X007T <sup>(1)</sup>
SMD-8, option 9	-	6N136-X009T <sup>(1)</sup>
<b>VDE, UL, CSA</b>	<b>≥ 7</b>	<b>≥ 19</b>
DIP-8	-	6N136-X001
DIP-8, 400 mil, option 6	-	6N136-X016
SMD-8, option 7	6N135-X017T <sup>(1)</sup>	6N136-X017T
SMD-8, option 9	-	6N136-X019T

#### Note

<sup>(1)</sup> Also available in tubes; do not add T to end

### ABSOLUTE MAXIMUM RATINGS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	25	mA
Peak forward current	t = 1 ms, duty cycle 50 %	I <sub>FSM</sub>	50	mA
Maximum surge forward current	t ≤ 1 μs, 300 pulses/s		1	A
Thermal resistance		R <sub>th</sub>	700	K/W
Power dissipation	T <sub>amb</sub> = 70 °C	P <sub>diss</sub>	45	mW



ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>OUTPUT</b>				
Supply voltage		$V_S$	- 0.5 to 15	V
Output voltage		$V_O$	- 0.5 to 15	V
Emitter base voltage		$V_{EBO}$	5	V
Output current		$I_O$	8	mA
Maximum output current			16	mA
Base current		$I_B$	5	mA
Thermal resistance			300	K/W
Power dissipation	$T_{amb} = 70\text{ }^{\circ}\text{C}$	$P_{diss}$	100	mW
<b>COUPLER</b>				
Isolation test voltage between emitter and detector	$t = 1\text{ s}$	$V_{ISO}$	5300	$V_{RMS}$
Pollution degree (DIN VDE 0109)			2	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	$R_{IO}$	$\geq 10^{11}$	$\Omega$
Storage temperature range		$T_{stg}$	- 55 to + 125	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature <sup>(1)</sup>	max. $\leq 10\text{ s}$ , dip soldering $\geq 0.5\text{ mm}$ from case bottom	$T_{sld}$	260	$^{\circ}\text{C}$

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- <sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	$I_F = 16\text{ mA}$		$V_F$		1.33	1.9	V
Breakdown voltage	$I_R = 10\text{ }\mu\text{A}$		$V_{BR}$	5			V
Reverse current	$V_R = 5\text{ V}$		$I_R$		0.5	10	$\mu\text{A}$
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$		$C_O$		30		pF
Temperature coefficient, forward voltage	$I_F = 16\text{ mA}$		$\Delta V_F/\Delta T_A$		- 1.7		mV/ $^{\circ}\text{C}$
<b>OUTPUT</b>							
Logic low supply current	$I_F = 16\text{ mA}, V_O = \text{open}, V_{CC} = 15\text{ V}$		$I_{CCL}$		150		$\mu\text{A}$
Logic high supply current	$I_F = 0\text{ mA}, V_O = \text{open}, V_{CC} = 15\text{ V}$		$I_{CCH}$		0.01	1	$\mu\text{A}$
Output voltage, output low	$I_F = 16\text{ mA}, I_O = 1.1\text{ mA}, V_{CC} = 4.5\text{ V}$	6N135	$V_{OL}$		0.1	0.4	V
	$I_F = 16\text{ mA}, I_O = 2.4\text{ mA}, V_{CC} = 4.5\text{ V}$	6N136	$V_{OL}$		0.1	0.4	V
Output current, output high	$I_F = 0\text{ mA}, V_O = V_{CC} = 5.5\text{ V}$		$I_{OH}$		3	500	nA
	$I_F = 0\text{ mA}, V_O = V_{CC} = 15\text{ V}$		$I_{OH}$		0.01	1	$\mu\text{A}$
<b>COUPLER</b>							
Capacitance (input to output)	$f = 1\text{ MHz}$		$C_{IO}$		0.6		pF

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



<b>CURRENT TRANSFER RATIO</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 16\text{ mA}$ , $V_O = 0.4\text{ V}$ , $V_{CC} = 4.5\text{ V}$	6N135	CTR	7	16		%
		6N136	CTR	19	35		%
	$I_F = 16\text{ mA}$ , $V_O = 0.5\text{ V}$ , $V_{CC} = 4.5\text{ V}$	6N135	CTR	5			%
		6N136	CTR	15			%

<b>SWITCHING CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
High to low	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 4.1\text{ k}\Omega$	6N135	$t_{PHL}$		0.3	1.5	$\mu\text{s}$
	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1.9\text{ k}\Omega$	6N136	$t_{PHL}$		0.2	0.8	$\mu\text{s}$
Low to high	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 4.1\text{ k}\Omega$	6N135	$t_{PLH}$		0.3	1.5	$\mu\text{s}$
	$I_F = 16\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1.9\text{ k}\Omega$	6N136	$t_{PLH}$		0.2	0.8	$\mu\text{s}$

<b>COMMON MODE TRANSIENT IMMUNITY</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
High	$I_F = 0\text{ mA}$ , $V_{CM} = 10\text{ V}_{P-P}$ , $V_{CC} = 5\text{ V}$ , $R_L = 4.1\text{ k}\Omega$	6N135	$ C_{MH} $		1000		$\text{V}/\mu\text{s}$
	$I_F = 0\text{ mA}$ , $V_{CM} = 10\text{ V}_{P-P}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1.9\text{ k}\Omega$	6N136	$ C_{MH} $		1000		$\text{V}/\mu\text{s}$
Low	$I_F = 16\text{ mA}$ , $V_{CM} = 10\text{ V}_{P-P}$ , $V_{CC} = 5\text{ V}$ , $R_L = 4.1\text{ k}\Omega$	6N135	$ C_{ML} $		1000		$\text{V}/\mu\text{s}$
	$I_F = 16\text{ mA}$ , $V_{CM} = 10\text{ V}_{P-P}$ , $V_{CC} = 5\text{ V}$ , $R_L = 1.9\text{ k}\Omega$	6N136	$ C_{ML} $		1000		$\text{V}/\mu\text{s}$

<b>SAFETY AND INSULATION RATINGS</b>							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
$V_{IOTM}$			8000			V	
$V_{IORM}$			890			V	
$P_{SO}$					500	mW	
$I_{SI}$					300	mA	
$T_{SI}$					175	$^{\circ}\text{C}$	
Creepage distance	Standard DIP-8		7			mm	
Clearance distance	Standard DIP-8		7			mm	
Creepage distance	400 mil DIP-8		8			mm	
Clearance distance	400 mil DIP-8		8			mm	

**Note**

- According to DIN EN 60747-5-2 (VDE 0884), this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

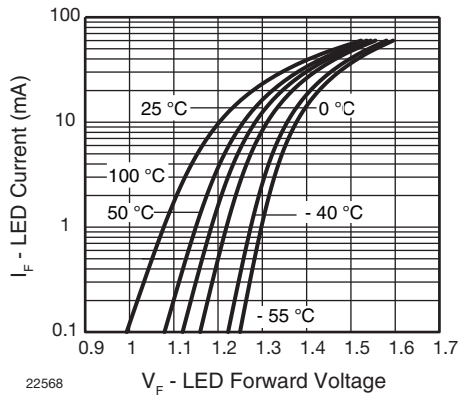


Fig. 1 - LED Forward Current vs. Forward Voltage

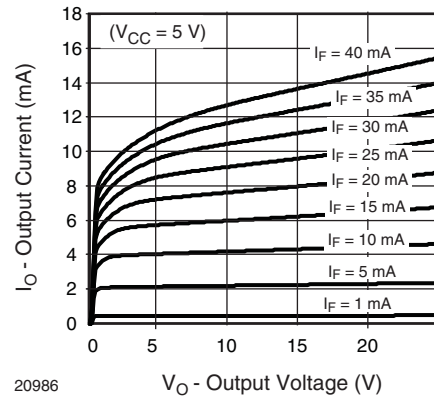


Fig. 4 - Output Current vs. Output Voltage

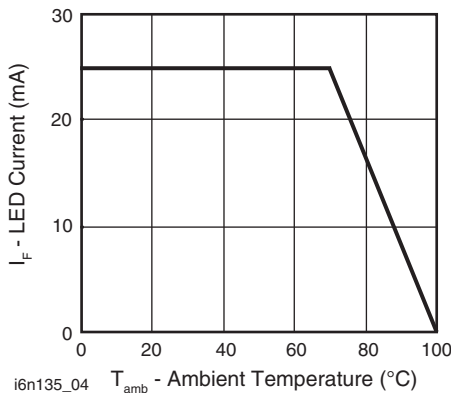


Fig. 2 - Permissible Forward LED Current vs. Temperature

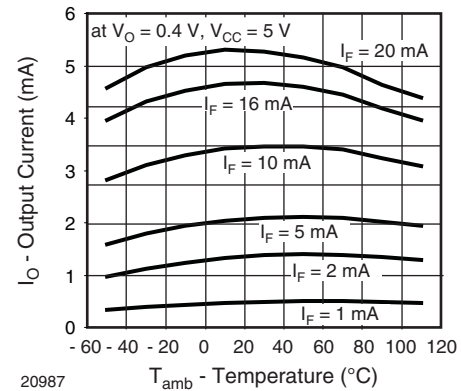


Fig. 5 - Output Current vs. Temperature

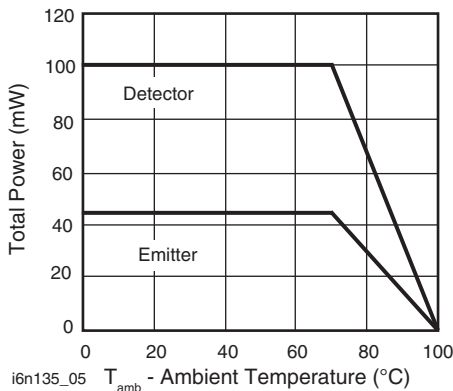


Fig. 3 - Permissible Power Dissipation vs. Temperature

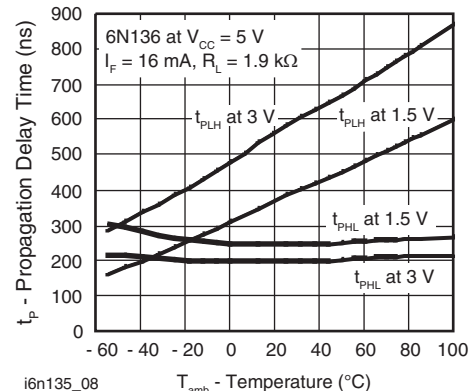


Fig. 6 - Propagation Delay vs. Ambient Temperature

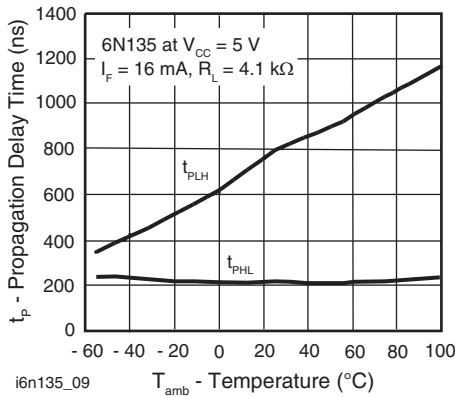


Fig. 7 - Propagation Delay vs. Ambient Temperature

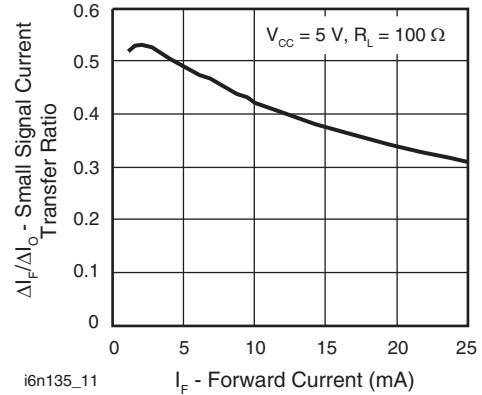


Fig. 9 - Small Signal Current Transfer Ratio vs. Quiescent Input Current

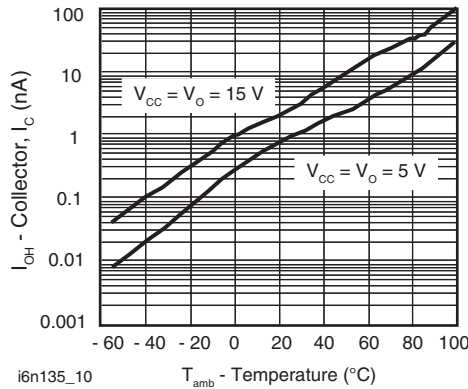


Fig. 8 - Logic High Output Current vs. Temperature

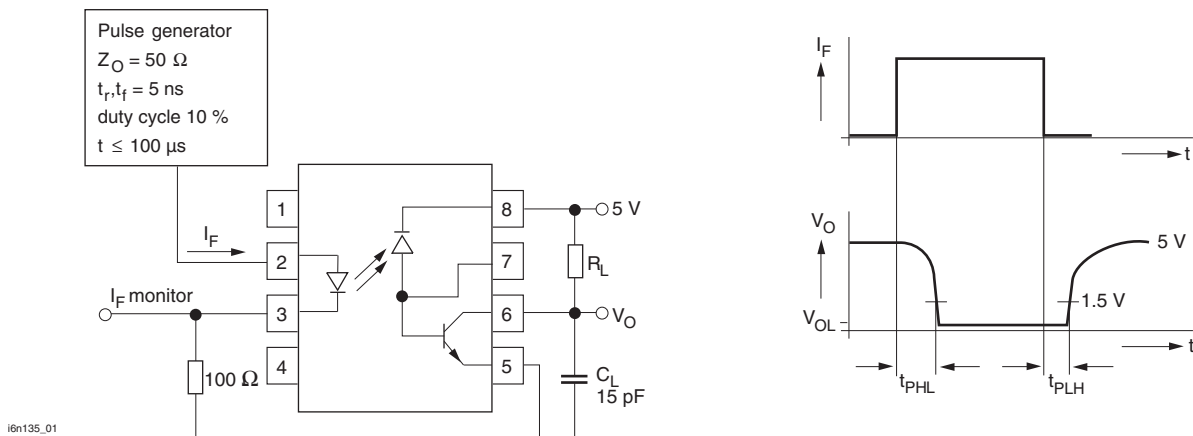


Fig. 10 - Switching Times

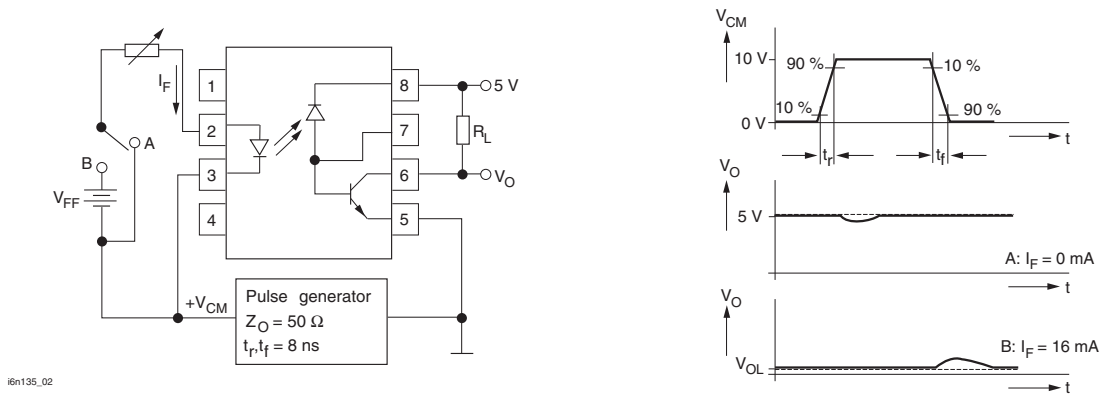
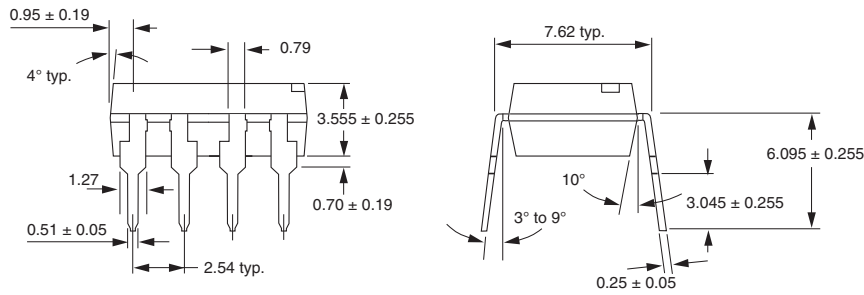
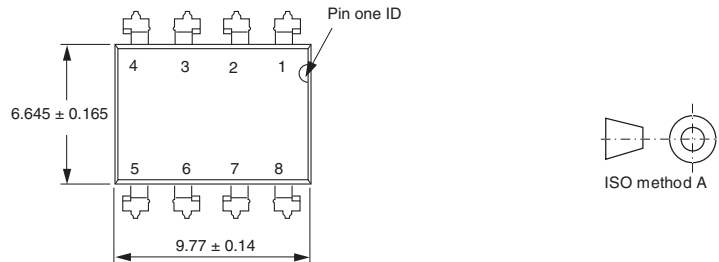
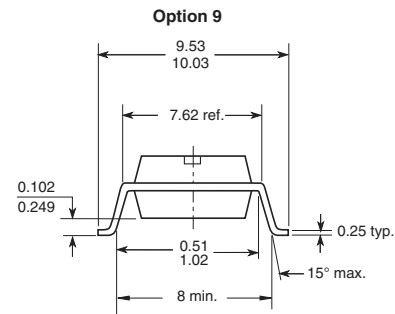
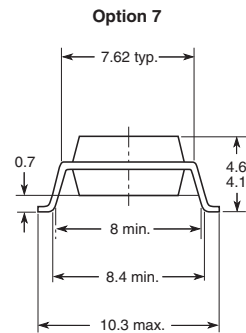
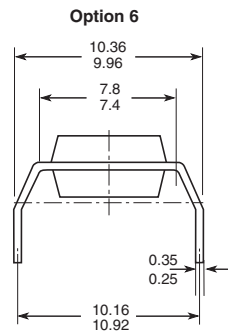


Fig. 11 - Common-Mode Interference Immunity

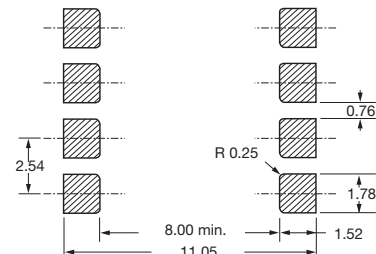
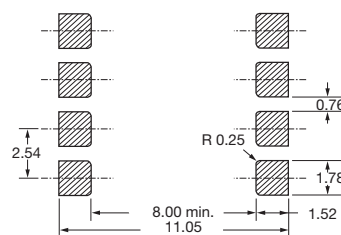
**PACKAGE DIMENSIONS** in millimeters



i178006



18450





**PACKAGE MARKING**



**Notes**

- Only options 1, and 7 are reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.



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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

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Электрон  
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